NSN 5961-01-509-3132

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-509-3132 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.165 inches and 0.195 inches **Overall Height:** Between 0.070 inches and 0.085 inches **Overall Width:** Between 0.070 inches and 0.085 inches **End Application:** Recorder-monitor **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 125.0 working peak reverse voltage **Current Rating Per Characteristic:** 500.00 milliamperes forward current, average preset **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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